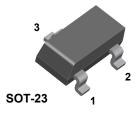
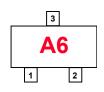
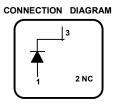


#### **BAS16**







## **High Conductance Ultra Fast Diode**

Sourced from Process 1P. See BAV99 for characteristics.

#### **Absolute Maximum Ratings\*** TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
W <sub>IV</sub>	Working Inverse Voltage	75	V
I <sub>F(AV)</sub>	Average Rectified Current	200	mA
I <sub>FM</sub>	DC Forward Current	600	mA
I <sub>FRM</sub>	Recurrent Peak Forward Current	700	mA
I <sub>FSM</sub>	Non-repetitive Peak Forward Surge Current Pulse width = 1.0 second Pulse width = 1.0 microsecond	1.0 2.0	A A
T <sub>stg</sub>	Storage Temperature Range	-50 to +150	°C
TJ	Operating Junction Temperature	150	°C

<sup>\*</sup>These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

#### Thermal Characteristics TA = 25°C unless otherwise noted

Symbol	Parameter	Max	Units
		BAS16	
P <sub>D</sub>	Total Device Dissipation	350	mW
	Derate above 25°C	2.8	mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	°C/W

#### **High Conductance Ultra Fast Diode**

(continued)

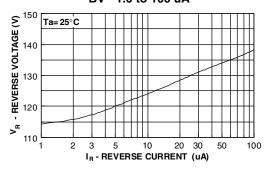
**Electrical Characteristics** 

TA = 25°C unless otherwise noted

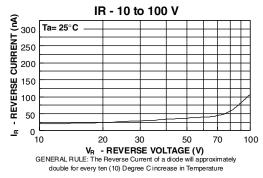
Symbol	Parameter	Test Conditions	Min	Max	Units
$V_R$	Breakdown Voltage	I <sub>R</sub> = 5.0 μA	85		V
I <sub>RM</sub>	Maximum Instantaneous Reverse Current	V <sub>R</sub> = 25 V, T <sub>A</sub> = 150°C V <sub>R</sub> = 75 V V <sub>R</sub> = 75 V, T <sub>A</sub> = 150°C		30 1.0 50	μΑ μΑ μΑ
V <sub>FM</sub>	Maximum Instantaneous Forward Voltage	I <sub>F</sub> = 1.0 mA I <sub>F</sub> = 10 mA I <sub>F</sub> = 50 mA I <sub>F</sub> = 150 mA		715 855 1.0 1.25	mV mV V
Со	Diode Capacitance	V <sub>R</sub> = 0, f = 1.0 MHz		2.0	pF
t <sub>rr</sub>	Reverse Recovery Time	$I_F = 10 \text{ mA}, V_R = 6.0 \text{ V},$ $I_{RR} = 1.0 \text{ mA}, R_L = 100\Omega$		6.0	ns

#### **Typical Characteristics**

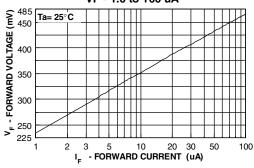
#### REVERSE VOLTAGE vs REVERSE CURRENT BV - 1.0 to 100 uA



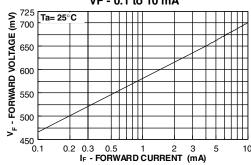
#### **REVERSE CURRENT vs REVERSE VOLTAGE**



## FORWARD VOLTAGE vs FORWARD CURRENT VF - 1.0 to 100 uA



## FORWARD VOLTAGE vs FORWARD CURRENT VF - 0.1 to 10 mA

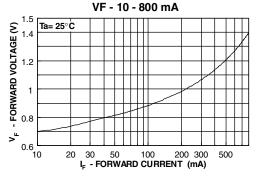


#### **High Conductance Ultra Fast Diode**

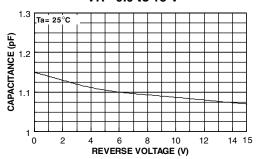
(continued)

#### Typical Characteristics (continued)

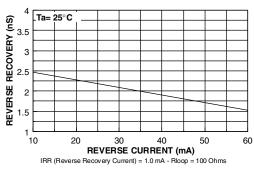
#### FORWARD VOLTAGE vs FORWARD CURRENT



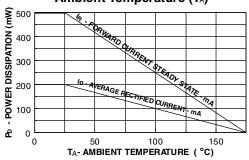
#### CAPACITANCE vs REVERSE VOLTAGE VR - 0.0 to 15 V



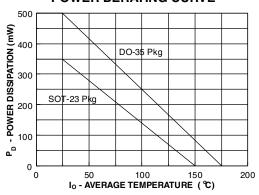
## REVERSE RECOVERY TIME vs REVERSE CURRENT TRR - IR 10 mA vs 60 mA



# Average Rectified Current (Io) & Forward Current (I<sub>F</sub>) versus Ambient Temperature (T<sub>A</sub>)



#### **POWER DERATING CURVE**

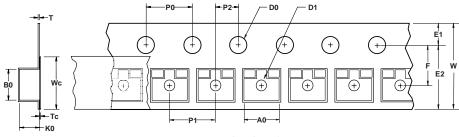




### SOT-23 Tape and Reel Data, continued

#### **SOT-23 Embossed Carrier Tape**

Configuration: Figure 3.0



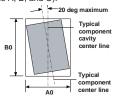
User Direction of Feed	

	Dimensions are in millimeter													
Pkg type	Α0	В0	w	D0	D1	E1	E2	F	P1	P0	K0	Т	Wc	Тс
<b>SOT-23</b> (8mm)	3.15 +/-0.10	2.77 +/-0.10	8.0 +/-0.3	1.55 +/-0.05	1.125 +/-0.125	1.75 +/-0.10	6.25 min	3.50 +/-0.05	4.0 +/-0.1	4.0 +/-0.1	1.30 +/-0.10	0.228 +/-0.013	5.2 +/-0.3	0.06 +/-0.02

Notes: A0, B0, and K0 dimensions are determined with respect to the EIA/Jedec RS-481 rotational and lateral movement requirements (see sketches A, B, and C).



Sketch A (Side or Front Sectional View)
Component Rotation

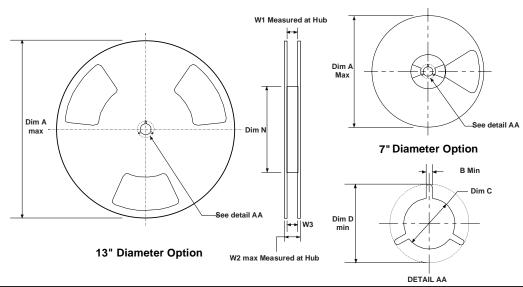


Sketch B (Top View)
Component Rotation



Sketch C (Top View)
Component lateral movement

#### SOT-23 Reel Configuration: Figure 4.0



	Dimensions are in inches and millimeters								
Tape Size	Reel Option	Dim A	Dim B	Dim C	Dim D	Dim N	Dim W1	Dim W2	Dim W3 (LSL-USL)
8mm	7" Dia	7.00 177.8	0.059 1.5	512 +0.020/-0.008 13 +0.5/-0.2	0.795 20.2	2.165 55	0.331 +0.059/-0.000 8.4 +1.5/0	0.567 14.4	0.311 - 0.429 7.9 - 10.9
8mm	13" Dia	13.00 330	0.059 1.5	512 +0.020/-0.008 13 +0.5/-0.2	0.795 20.2	4.00 100	0.331 +0.059/-0.000 8.4 +1.5/0	0.567 14.4	0.311 - 0.429 7.9 - 10.9



## SOT-23 (FS PKG Code 49)

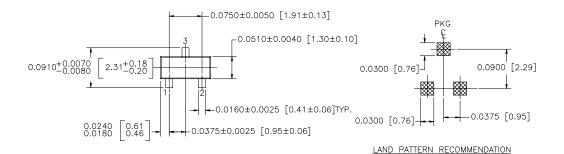


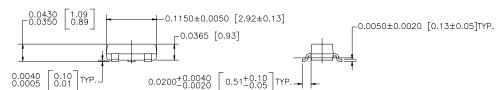


Scale 1:1 on letter size paper

Dimensions shown below are in: inches [millimeters]

Part Weight per unit (gram): 0.0082





CONTROLLING DIMENSION IS INCH VALUES IN [ ] ARE MILLIMETERS SOT 23, 3 LEADS LOW PROFILE

NOTE : UNLESS OTHERWISE SPECIFIED

- 1. STANDARD LEAD FINISH 150 MICROINCHES / 3.81 MICROMETERS MINIMUM TIN / LEAD (SOLDER) ON ALLOY 42
- 2. REFERENCE JEDEC REGISTRATION TO-236, VARIATION AB, ISSUE G, DATED JUL 1993

#### **TRADEMARKS**

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

 $ACEx^{TM}$ FASTr™ PowerTrench® SyncFET™ Bottomless™ QFET™ TinyLogic™ GlobalOptoisolator™ QSTM UHC™ CoolFET™ GTO™ **VCX**<sup>TM</sup>  $CROSSVOLT^{TM}$ QT Optoelectronics™ HiSeC™

DOME™ ISOPLANAR™ Quiet Series™

#### **DISCLAIMER**

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

#### LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.

2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

#### PRODUCT STATUS DEFINITIONS

#### **Definition of Terms**

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.